



PId Front end chip: PIF

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Requirement reminder

• Time measurement

- ♦ 100ps resolution max
- ♦ 1MHz background rate max
- 50ns double pulse resolution min

Charge measurement

- \forall necessary?
- ♦ dynamic range?
- ♦ fine or coarse?

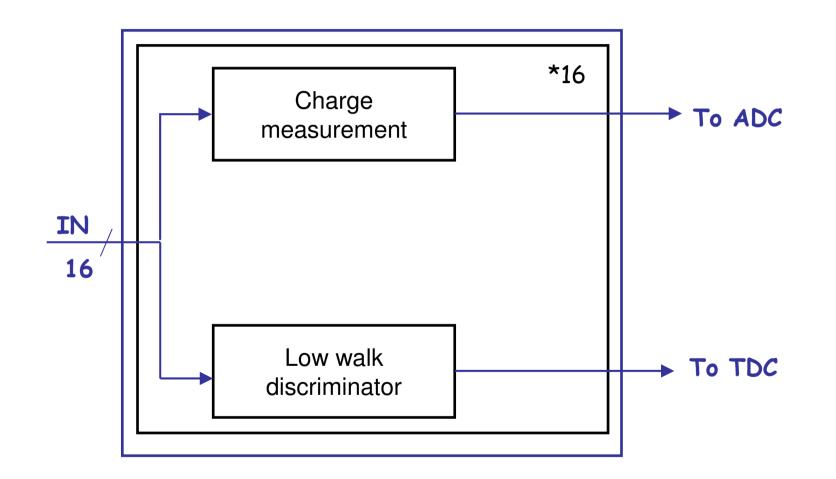
• PM monitoring

- ♦ fine or coarse? (signal reconstruction or charge measurement)
- ♦ during dedicated runs?



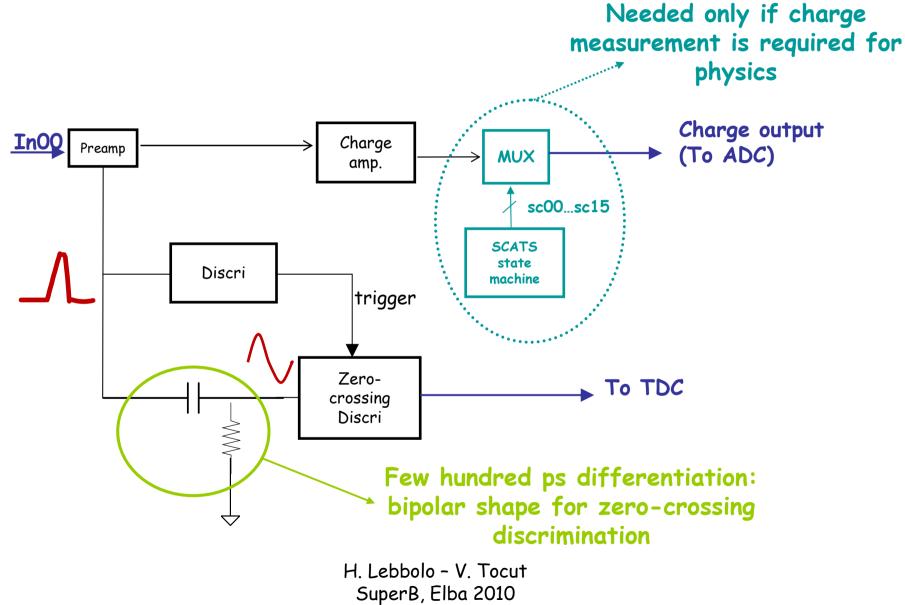
Proposal #1: Babar like

♦ 'CFD' like





Proposal #1: Babar like (cfd)





Prop. #1: Babar like (cfd)

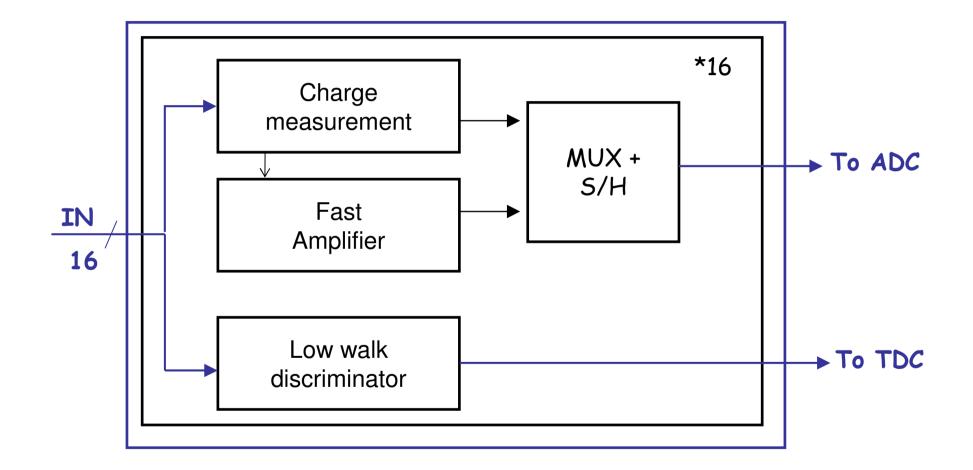
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 No walk correction if walk < 50ps (depending on PM dynamics) 	 « Time + charge » data synchronization (if charge is required for physics) Coarse charge measurement Necessity to know the peak jitter No fine PM monitoring

2 different chips developed:

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    analog front end {PIF}: Simple zero-crossing design but discrimination at peak
    beak
    could be available soon in a well-known (and existing) technology
    time measurement {SCATS}
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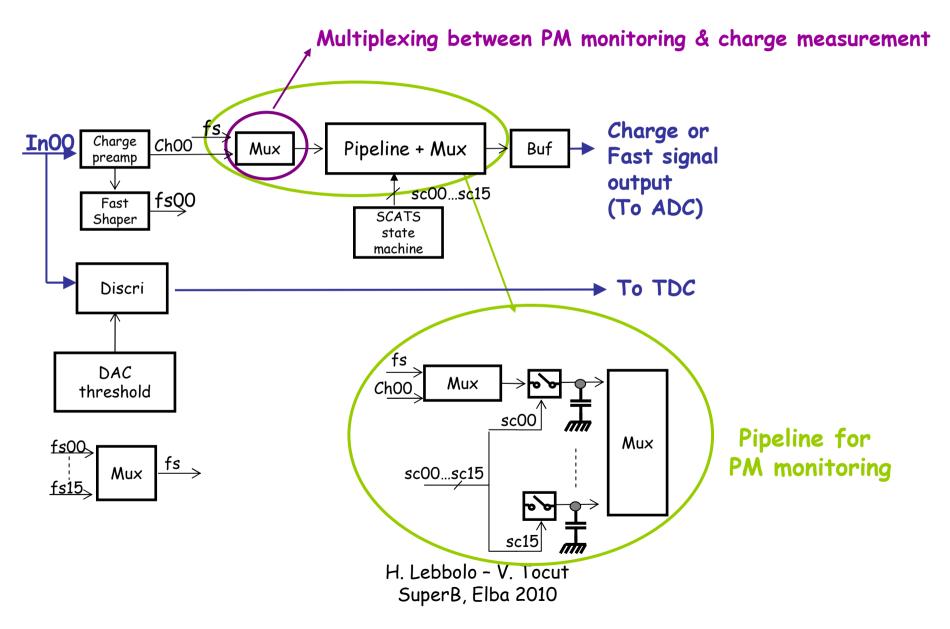


Prop. #2: upgraded prop #1



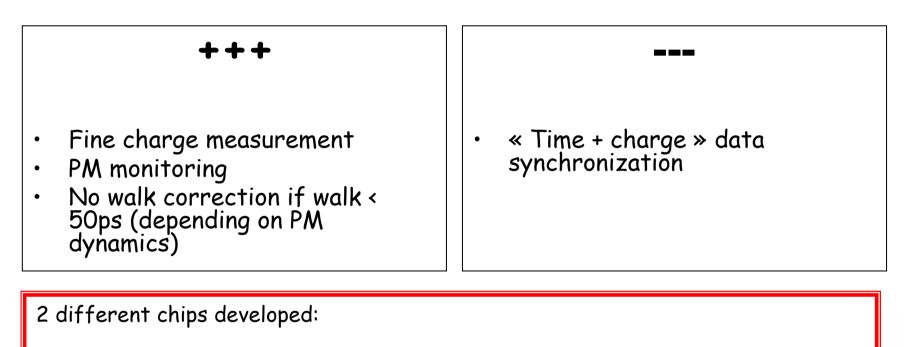


Prop. #2: upgraded prop #1



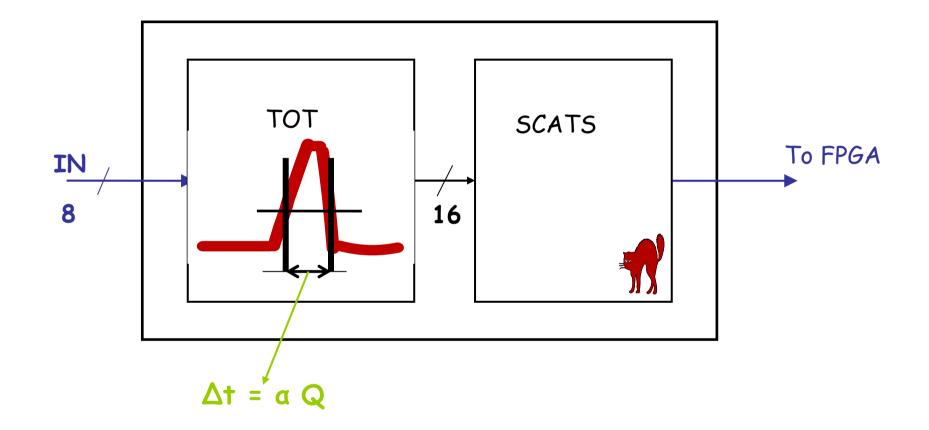


Prop. #2: upgraded prop #1



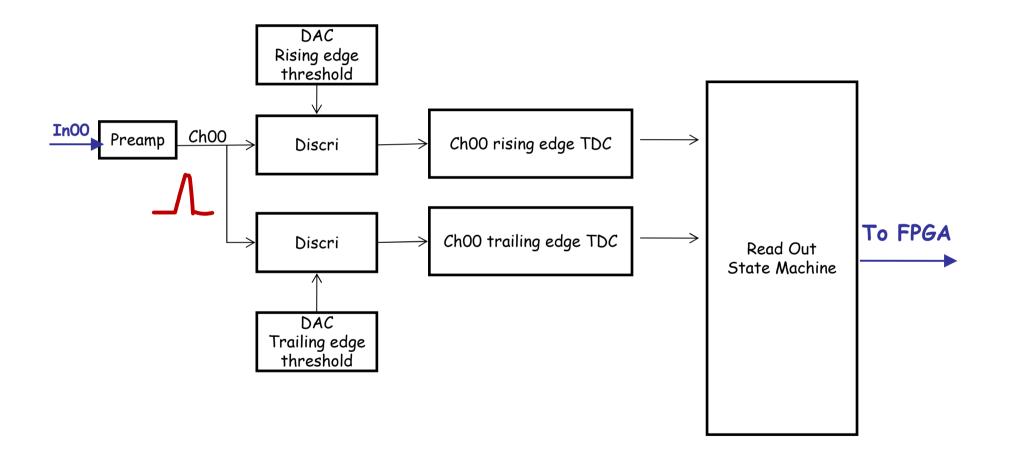
analog front end + monitoring {PIF}
time measurement {SCATS}







Proposal #3: TOT





Proposal #3: TOT

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 No « Time + charge » data synchronization problem Only 1 chip (discri + time in SCATS) 	 PM signals need to be very reproductible No PM monitoring or very coarse No precise charge measurement Number of channels for time measurement has to be doubled

2 different chips developed:

Physic dedicated {TOT+SCATS}: \$\$ simple (SCATS almost already exists)
 \$\$ available soon in a well-known (and existing)
 technology

Monitoring dedicated IC



Charge measurement
PM dynamic range
PM monitoring: precise or not?
Signal reproductibility
Peak jitter

>To be defined ASAP



Milestones

- In case of prop.#1 or 2:
 - \succ first simulations with XFAB 0.18 μ m CMOs tech.: end of June
 - design with AMS 0.18µm CMOS tech.: unknown (tech not available for the moment)
- In case of prop.#3:
 - > first simulations with AMS 0.35μ m CMOs tech.: end of June
 - design with AMS 0.35µm CMOS tech.: autumn (in collaboration with LPC Caen)